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High Performance Schottky Rectifier, 20 A



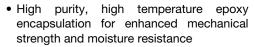
LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS							
I _{F(AV)} 20 A							
V_{R}	35 V, 40 V, 45 V						
V _F at I _F	0.51 V						
I _{RM} typ.	105 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	27 mJ						
Package	TO-220AC 2L						
Circuit configuration	Single						

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-20TQ... Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AC 2L Molding compound meets UL 94-V0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	20	Α					
V _{RRM}	Range	35 to 45	V					
I _{FSM}	t _p = 5 μs sine	1800	Α					
V _F	20 A _{pk} , T _J = 125 °C	0.51	V					
TJ	Range	-55 to +150	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-20TQ035-M3	VS-20TQ040-M3	VS-20TQ045-M3	UNITS			
Maximum DC reverse voltage	V_R							
Maximum working peak reverse voltage	V_{RWM}	35	40	45	V			

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 116 °C	20						
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	s sine or 3 µs rect. pulse Following any rated load		Α				
non-repetitive surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	400					
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 4 A, L = 3.4 mH		27	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		4	А				



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		20 A	T _{.1} = 25 °C	0.57				
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	40 A	1J=25 C	0.73	V			
	VFM (**)	20 A	T _{.1} = 125 °C	0.51	V			
		40 A	1J = 125 C	0.67				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	2.7	A			
Maximum reverse leakage current		T _J = 125 °C	v _R = nateu v _R	150	mA			
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	$T_J = 125 ^{\circ}\text{C}$ $V_R = \text{Rated } V_R$		mA			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} , (test signal range 100 kHz to 1 MHz) 25 °C		1400	pF			
Typical series inductance	L _S	Measured lead to lead 5 m	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

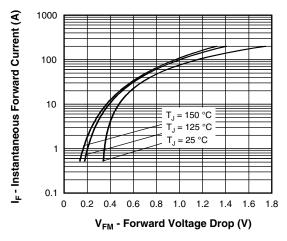
 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.50	°C/M				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, and greased	0.50	°C/W				
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
Maation toward	imum		6 (5)	kgf ⋅ cm				
Mounting torque max	rimum		12 (10)	(lbf \cdot in)				
			20T0	2035				
Marking device		Case style TO-220AC 2L	20T0	Q040				
			20T0	Q045				

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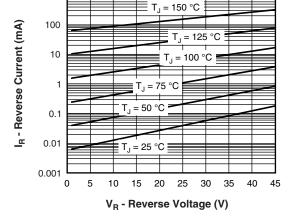


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

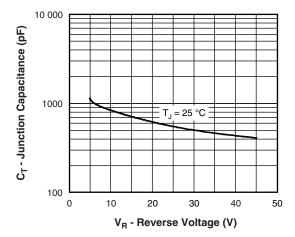


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

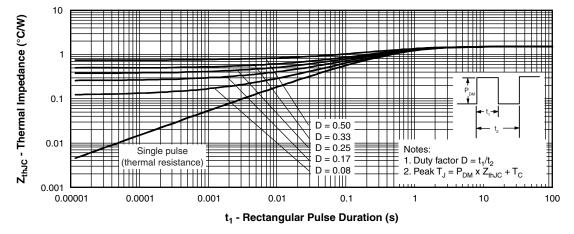


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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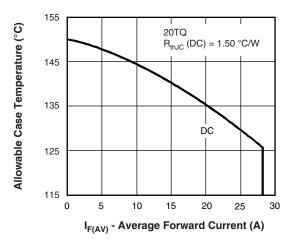


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

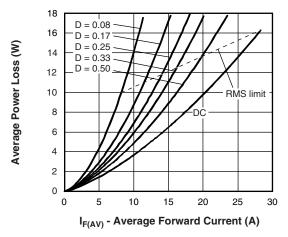


Fig. 6 - Forward Power Loss Characteristics

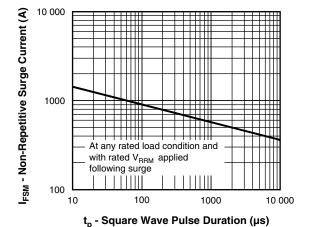


Fig. 7 - Maximum Non-Repetitive Surge Current

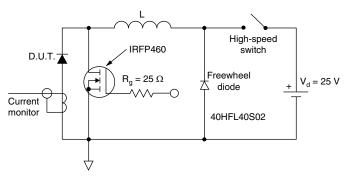
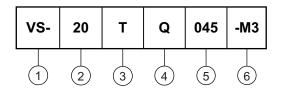


Fig. 8 - Unclamped Inductive Test Circuit

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Current rating (20 = 20 A)

Package:

T = TO-220

Schottky "Q" series

035 = 35 V 040 = 40 VVoltage ratings

045 = 45 VEnvironmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-20TQ035-M3	50	Antistatic plastic tubes						
VS-20TQ040-M3	50	Antistatic plastic tubes						
VS-20TQ045-M3	50	Antistatic plastic tubes						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96156					
Part marking information	www.vishay.com/doc?95391					
SPICE model	www.vishay.com/doc?96917					



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TO-220AC 2L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES SY	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355				•	•			

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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